

Power Schottky rectifier

Main product characteristics

I _{F(AV)}	1 A
V _{RRM}	150 V
T _j (max)	175° C
V _F (max)	0.67 V

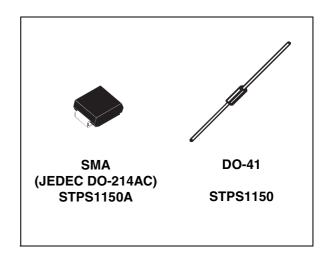
Description

150 V Power Schottky rectifier are suited for switch mode power supplies on up to 24 V rails and high frequency converters.

Packaged in SMA and Axial, this device is intended for use in consumer and computer applications like TV, STB, PC and DVD where low drop forward voltage is required to reduce power dissipation.

Order Codes

Part Number	Marking
STPS1150A	1150
STPS1150	STPS1150
STPS1150RL	STPS1150



Features and benefits

- Negligible switching losses
- Low forward voltage drop for higher efficiency and extented battery life
- Low thermal resistance
- Surface mount miniature package
- Avalanche capability specified

Table 1. Absolute Ratings (limiting values)

Symbol	Parameter			Value	Unit	
V _{RRM}	Repetitive peak reverse voltage			150	V	
I _{F(RMS)}	RMS forward voltage			15	Α	
1	Average forward current		$T_L = 160^{\circ} \text{ C} \delta = 0.5$	4	Α	
'F(AV)	I _{F(AV)} Average forward current	DO-41	$T_L = 150^{\circ} \text{ C} \delta = 0.5$	'		
	Surge non repetitive forward	SMA	t – 10 ma ainuacidal	50	А	
'FSM	rent current		$t_p = 10 \text{ ms sinusoidal}$	75		
P _{ARM}	Repetitive peak avalanche power $tp = 1\mu s$ $Tj = 25^{\circ}$ C			1500	W	
T _{stg}	Storage temperature range			-65 to + 150	° C	
T _j	Maximum operating junction temperature ⁽¹⁾			175	° C	

^{1.} $\frac{dPtot}{dTj} > \frac{1}{Rth(j-a)}$ thermal runaway condition for a diode on its own heatsink

Characteristics STPS1150

1 Characteristics

Table 2. Thermal resistance

Symbol	Parameter			Value	Unit
В	Junction to lead		SMA	20	° C/W
$R_{th(j-l)}$	Junction to lead	Lead length = 10 mm	DO-41	30	C/VV

Table 3. Static electrical characteristics

Symbol	Parameter	Tests conditions		Min.	Тур	Max.	Unit
ı (1)	I _R (1) Reverse leakage current –	T _j = 25° C	$V_R = V_{RRM}$		0.2	1.0	μΑ
'R`′		T _j = 125° C			0.2	1.0	mA
	V (2) Forward valtage drap	T _j = 25° C	I _F = 1 A		0.78	0.82	
V _F ⁽²⁾		T _j = 125° C			0.62	0.67	V
V _F ⁽²⁾ Forward voltage drop	T _j = 25° C			0.85	0.89	V	
		T _j = 125° C	I _F = 2 A		0.69	0.75	

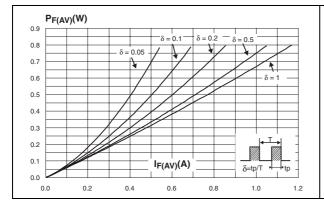
^{1.} $t_p = 5 \text{ ms}, \delta < 2\%$

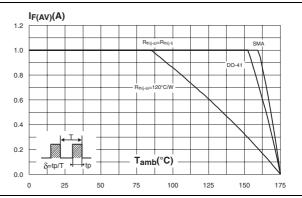
To evaluate the conduction losses use the following equation:

 $P = 0.59 \times I_{F(AV)} + 0.08 I_{F^{2}(RMS)}$

Figure 1. Average forward power dissipation versus average forward current

Figure 2. Average forward current versus ambient temperature (δ = 0.5)



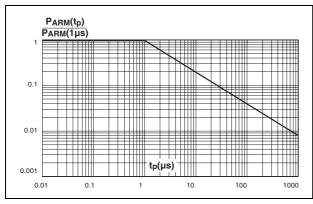


^{2.} $t_p = 380 \ \mu s, \ \delta < 2\%$

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Figure 3. Normalized avalanche power derating versus pulse duration

Figure 4. Normalized avalanche power derating versus junction temperature



PARM(tp)
PARM(25°C)

1.2

1

0.8

0.6

0.4

0.2

25

50

75

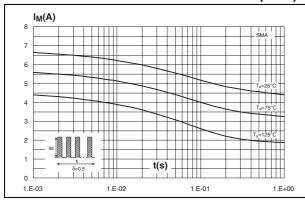
100

125

150

Figure 5. Non repetitive surge peak forward current versus overload duration - maximum values (SMA)

Figure 6. Non repetitive surge peak forward current versus overload duration - maximum values (DO-41)



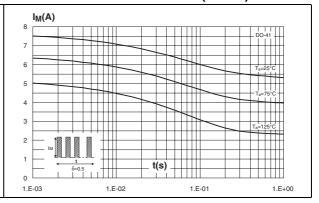
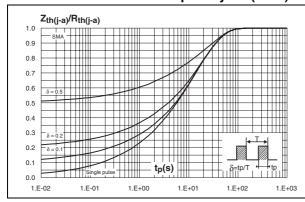
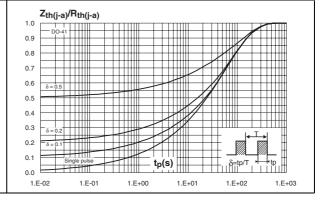


Figure 7. Relative variation of thermal impedance junction to ambient versus pulse duration - epoxy printed circuit board, e_{Cu} = 35 μ m, recommended pad layout (SMA)

Figure 8. Relative variation of thermal impedance junction to ambient versus pulse duration (DO-41)

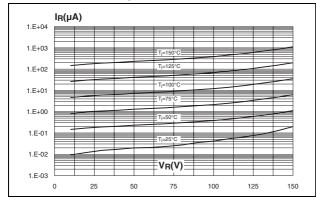




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Figure 9. Reverse leakage current versus reverse voltage applied (typical values)

Figure 10. Junction capacitance versus reverse voltage applied (typical values)



C(pF)

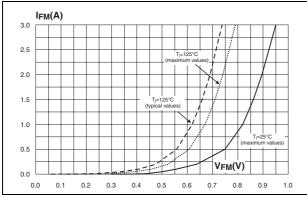
100

VR(V)

1 1 10 100 1000

Figure 11. Forward voltage drop versus forward current - maximum values, high level (SMA)

Figure 12. Forward voltage drop versus forward current - maximum values, low level (DO-41)



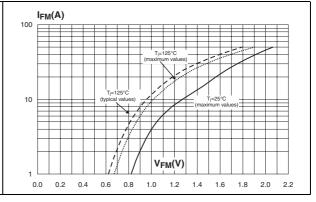
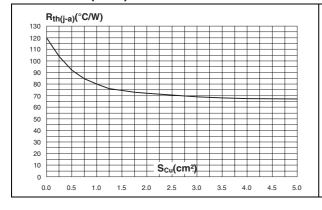
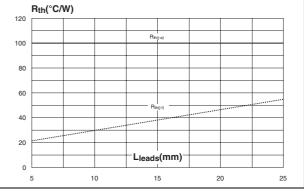


Figure 13. Thermal resistance junction to ambient versus copper surface under each lead - Epoxy printed circuit board FR4, e_{Cu} = 35 μm (SMA)

Figure 14. Thermal resistance versus lead length (DO-41)



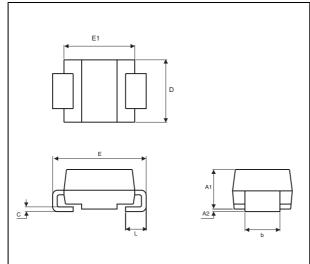


STPS1150 Package information

2 Package information

Band shows cathode. Epoxy meets UL94, V0.

Table 4. SMA Package dimensions



	DIMENSIONS			
REF.	Millimeters		Inc	hes
,	Min.	Max.	Min.	Max.
A1	1.90	2.03	0.075	0.080
A2	0.05	0.20	0.002	0.008
b	1.25	1.65	0.049	0.065
С	0.15	0.41	0.006	0.016
Е	4.80	5.60	0.189	0.220
E1	3.95	4.60	0.156	0.181
D	2.25	2.95	0.089	0.116
L	0.75	1.60	0.030	0.063

Figure 15. SMA Foot Print Dimensions (in mm)

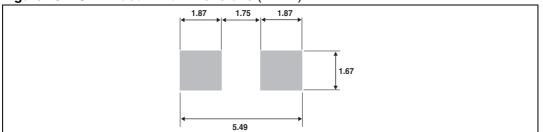
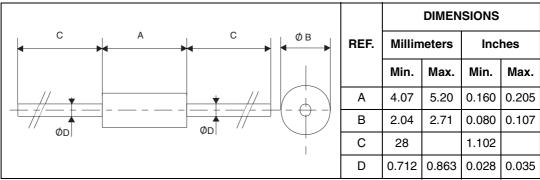


Table 5. DO-41 Package dimensions



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Ordering information STPS1150

3 Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS1150A	1150	SMA	0.068 g	5000	Tape and reel
STPS1150	STPS1150	DO-41	0.34 g	2000	Ammopack
STPS1150RL	STPS1150	DO-41	0.34 g	5000	Tape and reel

4 Revision history

Date	Revision	Description of Changes
Jul-2003	2A	Last update.
Aug-2004	3	SMA package dimensions update. Reference A1 max. changed from 2.70mm (0.106inc.) to 2.03mm (0.080).
31-May-2006	4	Reformatted to current standard. Added ECOPACK statement. Updated SMA footprint in Figure 15. Changed nF to pF in Figure 10.

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